

Citations for Ion : Ta

Pub. Year	Authors, Title, Journal Citation and Comments	Citation Numb
1966	VanLint, V. A. J. Wyatt, M. E. Schmitt, R. A. Suffredini, C. S. Nichols, D. K. 'Range of Photoparticle Recoil Atoms on Solids' <i>Phys. Rev., 147, 242-48 (1966)</i> Comment : R. (.001- 5 epsilon) Ti, Sc, Cr, Fe, Mn, Ni, Co, Ge, Zr, Y, Sr, Mo, Rh, Pd, Ag, Cd, Sn, Gd, Ta, Au, Th -> Al, Cu	1966-VanL
1967	Sperduto, A. Buechner, W. W. VanDeGraaff, R. J. 'Range-Energy Measurements for Heavy Ions' <i>Bull. Am. Phys. Soc., 12, 28c (1967)</i> Comment : R. 100-240 MeV F, Br, I, Ta, U -> Emulsion	1967-Sper
1969	Kalish, R. Grodzins, L. Chmara, F. Rose, P. H. 'Stopping Power of Solids for Fast Moving Tantalum Ions' <i>Phys. Rev., 183, 431-35 (1969)</i> Comment : S. 10-140 MeV Ta -> C, Al, Ag, Au	1969-Kali
1972	Bister, M. Anttila, A. Fontell, A. Leminen, E. 'A Method for the Determination of Recoil Ion Ranges Needed in Dsa Measurements' <i>Physik, 250, 82-86 (1972)</i> Comment : R. 50 keV Al -> C, Cu, Mo, Ta	1972-Bist
1976	Grant, W. A. Dodds, D. Williams, J. S. Christodoulides, C. E. Baragiola, R. A. 'Heavy Ion Ranges in Silicon and Aluminum' <i>Ion Implantation in Semiconductors, Ed. by F. Chernow, J. A. Borders, D. K. Brice, 693-703 (1976)</i> Comment : R. 0.01 < Epsilon < 0.8 Cr, Ni, Ga, As, Br, Mo, Cs, La, Nd, Dy, Ta, Pt, Au, Pb -> Si, Al	1976-Gran
1976	Sood, D. K. Dearnaley, G. 'Ion-Implanted Surface Alloys in Copper and Aluminum' <i>G. Carter, J. S. Colligon, W. A. Grant (Ed.): Appl. of Ion Beams to Materials. Inst. of Physics Conf. Ser. No. 28, 169-203 (1976)</i> Comment : R. (150-300) keV Au, Mo, Bi, Ta, Mo, Gd, Bi, Cu, Rb, Ru, Cs, Ce, Eu, Ag, Cu, Se, Au -> Cu; Rb, Cd, Cs -> Al.	1976-Sood
1993	Tikkanen, P. Keinonen, J. Kangasmaki, A. Fulop, Z. Kiss, A. Z. 'Short Lifetimes in Si-28' <i>Phys. Rev. C, 47, 145-156 (1993)</i> Comment : S. Ta (0-6 V/Vo) -> Si	1993-Tikk